

N-channel 60 V 11.3 mΩ logic level MOSFET in LFPAK33

4 June 2013

Product data sheet

### 1. General description

Logic level enhancement mode N-channel MOSFET in LFPAK33 package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

### 2. Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources
- LFPAK33 package is footprint compatible with other 3.3mm types
- Qualified to 175 °C

### 3. Applications

- AC-to-DC converters
- Synchronous rectification
- DC-DC converters

### 4. Quick reference data

Table 1. C	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C	-	-	60	V
I <sub>D</sub>	drain current	T <sub>mb</sub> = 25 °C; V <sub>GS</sub> = 10 V; <u>Fig. 1</u>	-	-	61	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	-	91	W
Tj	junction temperature		-55	-	175	°C
Static chara	acteristics	· · · · · · · · · · · · · · · · · · ·				
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 25 °C; Fig. 12	-	9.35	11.3	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>	-	11	13.1	mΩ
Dynamic cl	haracteristics	· · · · · ·				
Q <sub>GD</sub>	gate-drain charge	$V_{GS}$ = 4.5 V; $I_D$ = 15 A; $V_{DS}$ = 30 V; T <sub>j</sub> = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5.1	-	nC

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### 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D
2	S	source		
3	S	source		G-UTA
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)	

# 6. Ordering information

Cable 3.       Ordering information						
Type number	Package					
	Name	Description	Version			
PSMN011-60ML	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210			

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN011-60ML	M11L60

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

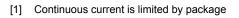
Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C	-	60	V
V <sub>GS</sub>	gate-source voltage		-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	61	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 1</u>	-	43	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$ ; Fig. 4	-	242	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	91	W
T <sub>stg</sub>	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C

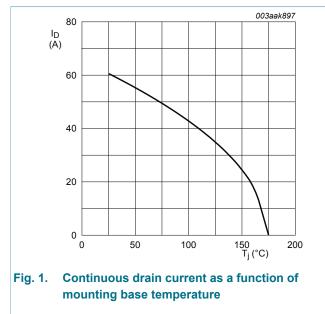
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# PSMN011-60ML

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Symbol	Parameter	Conditions		Min	Max	Unit
T <sub>sld(M)</sub>	peak soldering temperature			-	260	°C
Source-drai	in diode					
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	70	А
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^\circ C$		-	242	А
Avalanche	ruggedness					
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	$\label{eq:VGS} \begin{array}{l} V_{GS} \texttt{=} 10 \; V; \; T_{j(\text{init})} \texttt{=} 25 \; ^{\circ}C; \; I_{D} \texttt{=} 61 \; A; \\ V_{sup} \texttt{\leq} 60 \; V; \; R_{GS} \texttt{=} 50 \; \Omega; \; unclamped; \\ \hline Fig. 3 \end{array}$		-	48.5	mJ





 $V_{GS} \ge 10V$ 

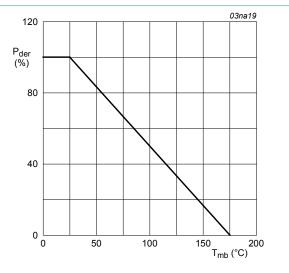
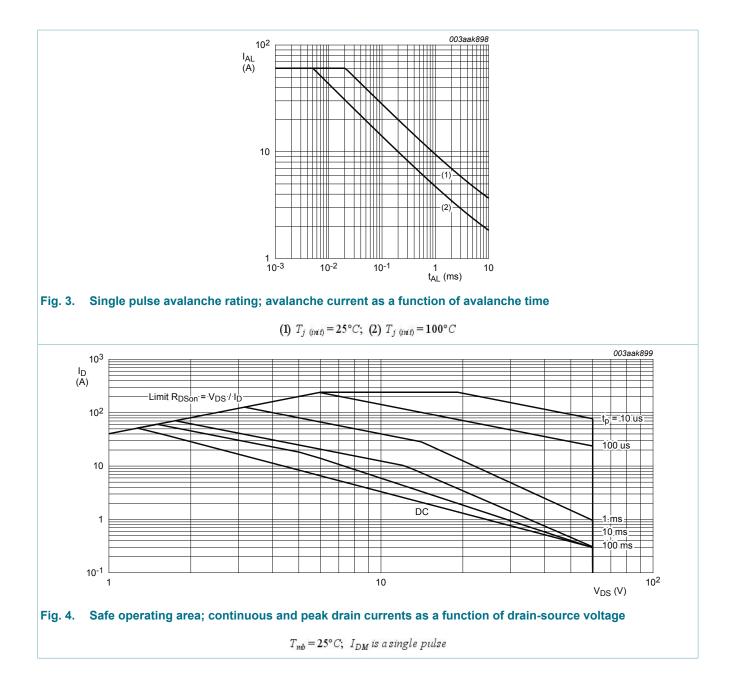


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

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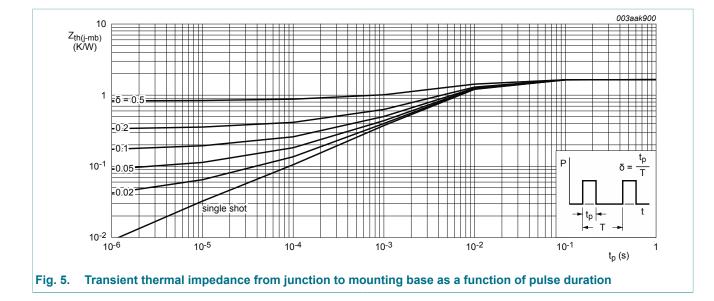
#### N-channel 60 V 11.3 m $\Omega$ logic level MOSFET in LFPAK33



### 9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	1.44	1.65	K/W

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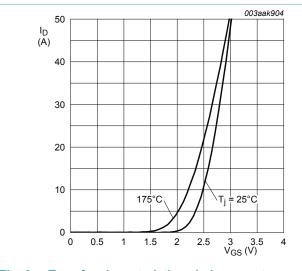


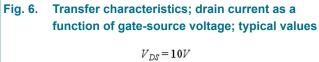
### **10. Characteristics**

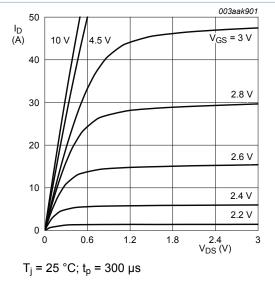
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	60	-	-	V
	breakdown voltage	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = -55 °C	54	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = -55 °C; Fig. 10	-	-	2.45	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C; Fig. 11; Fig. 10	1.3	1.7	2.15	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 175 °C; Fig. 10	0.5	-	-	V
	drain leakage current	$V_{DS}$ = 60 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	0.03	1	μA
		$V_{DS}$ = 60 V; $V_{GS}$ = 0 V; $T_j$ = 175 °C	-	-	500	μA
I <sub>GSS</sub>	breakdown voltage gate-source threshold voltage	$V_{GS}$ = 16 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	54V-54V2.45V1.31.72.15V0.5V-0.50.031 $\mu$ A500 $\mu$ A100nA100nA100nA24.8mΩ28.8mΩ			
		$V_{GS}$ = -16 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
Doon		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 25 °C; Fig. 12	-	9.35	11.3	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 25 °C; Fig. 12	-	11	13.1	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 175 °C; Fig. 12; Fig. 13	-	-	24.8	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 175 °C; Fig. 12; Fig. 13	-	-	28.8	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz	-	1.86	-	Ω

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic cl	haracteristics		I			
Q <sub>G(tot)</sub>	total gate charge	$I_{D} = 15 \text{ A}; V_{DS} = 30 \text{ V}; V_{GS} = 10 \text{ V};$ $T_{j} = 25 \text{ °C}; \underline{\text{Fig. 14}}; \underline{\text{Fig. 15}}$	-	37.2	-	nC
		$I_D$ = 15 A; $V_{DS}$ = 30 V; $V_{GS}$ = 4.5 V;	-	16.6	-	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5	-	nC
Q <sub>GD</sub>	gate-drain charge		-	5.1	-	nC
V <sub>GS(pl)</sub>	gate-source plateau voltage	I <sub>D</sub> = 15 A; V <sub>DS</sub> = 30 V; T <sub>j</sub> = 25 °C; <u>Fig. 14; Fig. 15</u>	-	2.75	-	V
C <sub>iss</sub>	input capacitance	$V_{DS}$ = 30 V; $V_{GS}$ = 0 V; f = 1 MHz; T <sub>j</sub> = 25 °C; Fig. 16	-	2191	-	pF
C <sub>oss</sub>	output capacitance	$V_{DS}$ 30 V; $V_{GS}$ = 0 V; f = 1 MHz; T <sub>j</sub> = 25 °C; Fig. 16	-	199	-	pF
C <sub>rss</sub>	reverse transfer capacitance	V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 0 V; f = 1 MHz; T <sub>j</sub> = 25 °C; <u>Fig. 16</u>	-	111	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 30 V; R <sub>L</sub> = 2 Ω; V <sub>GS</sub> = 4.5 V;	-	13.3	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	20.2	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	27.7	-	ns
t <sub>f</sub>	fall time		-	15.5	-	ns
Source-dra	in diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 15 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <u>Fig. 17</u>	-	0.84	1.2	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 15 A; dI <sub>S</sub> /dt = -100 A/µs; V <sub>GS</sub> = 0 V;	-	20.7	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 30 V; T <sub>j</sub> = 25 °C	-	15.7	-	nC

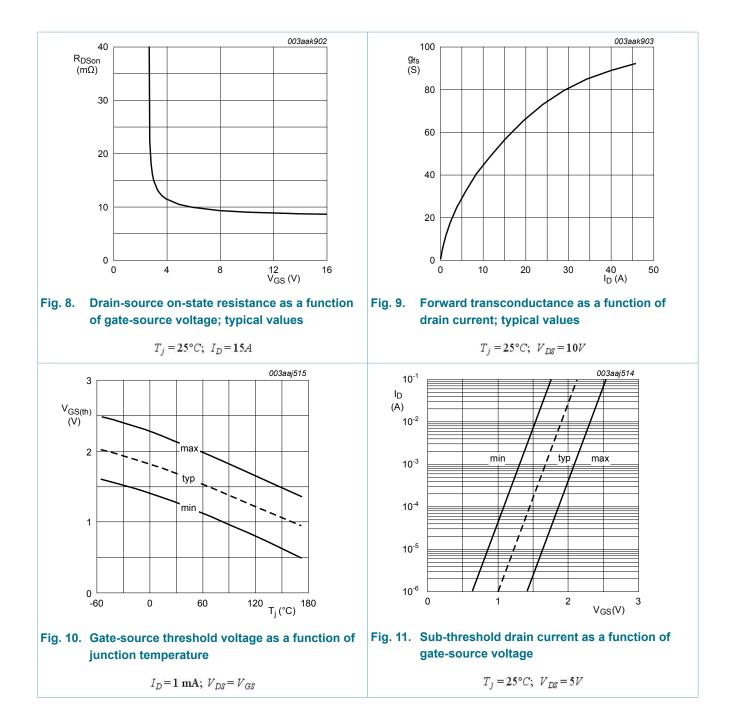






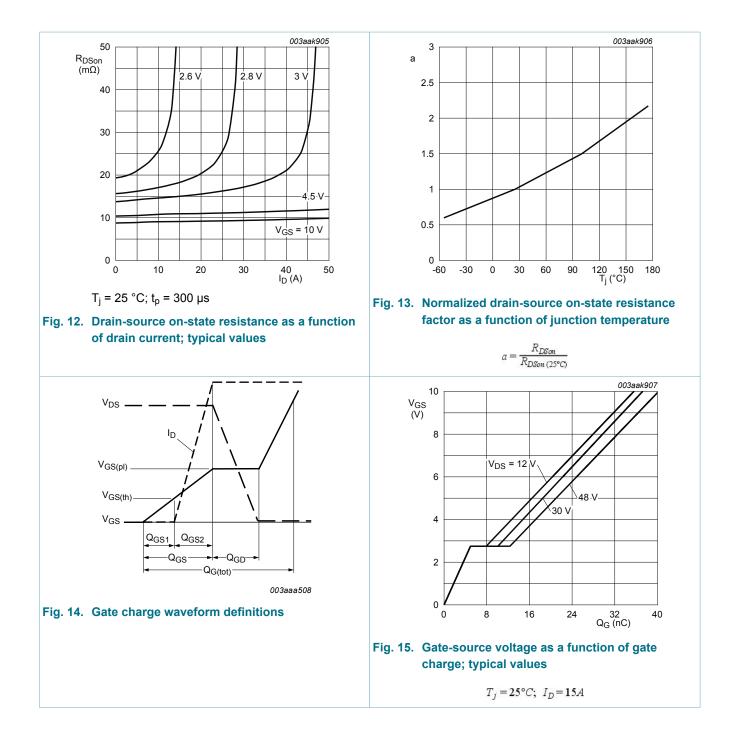


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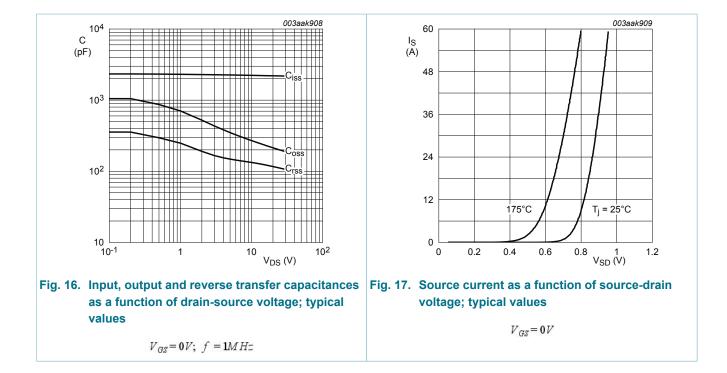
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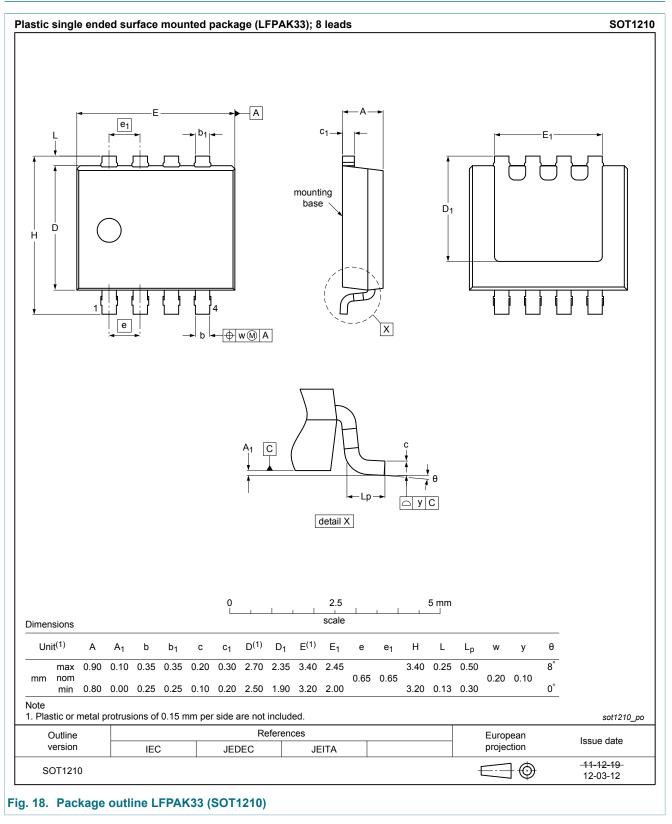
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### 11. Package outline



PSMN011-60ML

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### 12. Legal information

#### 12.1 Data sheet status

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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